

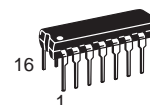
8-Bit Serial-Input/Serial or Parallel-Output Shift Register with Latched 3-State Outputs

High-Performance Silicon-Gate CMOS

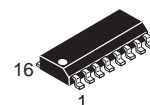
The 74HC595A consists of an 8-bit shift register and an 8-bit D-type latch with three-state parallel outputs. The shift register accepts serial data and provides a serial output. The shift register also provides parallel data to the 8-bit latch. The shift register and latch have independent clock inputs. This device also has an asynchronous reset for the shift register.

The HC595A directly interfaces with the SPI serial data port on CMOS MPUs and MCUs.

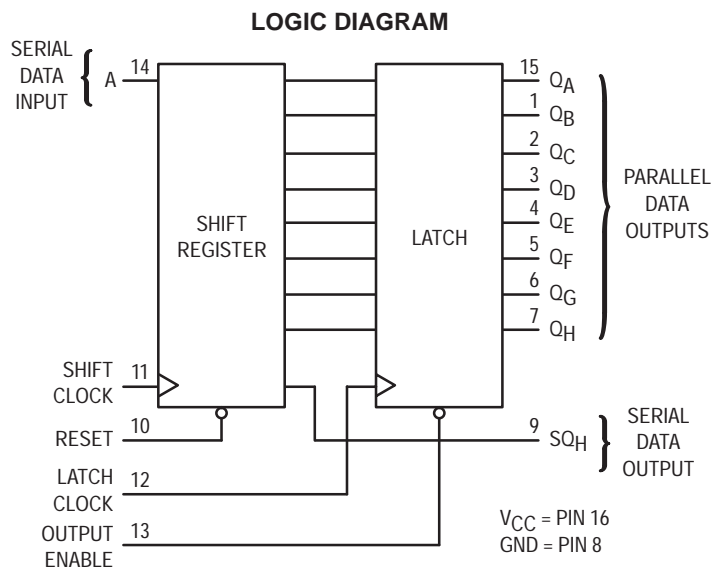
- Output Drive Capability: 15 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1.0 μ A
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 328 FETs or 82 Equivalent Gates
- Improvements over HC595
 - Improved Propagation Delays
 - 50% Lower Quiescent Power
 - Improved Input Noise and Latchup Immunity



**DIP-16
N SUFFIX
CASE 648**



**SOP-16
D SUFFIX
CASE 751B**



PIN ASSIGNMENT

| | | | |
|-----|---|----|---------------|
| QB | 1 | 16 | VCC |
| QC | 2 | 15 | QA |
| QD | 3 | 14 | A |
| QE | 4 | 13 | OUTPUT ENABLE |
| QF | 5 | 12 | LATCH CLOCK |
| QG | 6 | 11 | SHIFT CLOCK |
| QH | 7 | 10 | RESET |
| GND | 8 | 9 | SQH |

ORDERING INFORMATION

| Device | Package | Shipping |
|-------------|---------|-------------|
| 74HC595N | DIP-16 | 2000 / Box |
| 74HC595M/TR | SOP-16 | 2500 / Reel |

MAXIMUM RATINGS*

| Symbol | Parameter | Value | Unit |
|------------------|--|--------------------------------|------|
| V _{CC} | DC Supply Voltage (Referenced to GND) | - 0.5 to + 7.0 | V |
| V _{in} | DC Input Voltage (Referenced to GND) | - 0.5 to V _{CC} + 0.5 | V |
| V _{out} | DC Output Voltage (Referenced to GND) | - 0.5 to V _{CC} + 0.5 | V |
| I _{in} | DC Input Current, per Pin | ± 20 | mA |
| I _{out} | DC Output Current, per Pin | ± 35 | mA |
| I _{CC} | DC Supply Current, V _{CC} and GND Pins | ± 75 | mA |
| P _D | Power Dissipation in Still Air, Plastic DIP† SOIC Package† TSSOP Package† | 750 500 450 | mW |
| T _{stg} | Storage Temperature | - 65 to + 150 | °C |
| T _L | Lead Temperature, 1 mm from Case for 10 Seconds | 260 | °C |

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND ≤ (V_{in} or V_{out}) ≤ V_{CC}. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

*Maximum Ratings are those values beyond which damage to the device may occur.

Functional operation should be restricted to the Recommended Operating Conditions.

†Derating — Plastic DIP: - 10 mW/°C from 65° to 125°C

SOP Package: - 7 mW/°C from 65° to 125°C

For high frequency or heavy load considerations, see Chapter 2 of the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|------------------------------------|--|--|--------------------|------|
| V _{CC} | DC Supply Voltage (Referenced to GND) | 2.0 | 6.0 | V |
| V _{in} , V _{out} | DC Input Voltage, Output Voltage (Referenced to GND) | 0 | V _{CC} | V |
| T _A | Operating Temperature, All Package Types | - 55 | + 125 | °C |
| t _r , t _f | Input Rise and Fall Time (Figure 1) | V _{CC} = 2.0 V 0 V _{CC} = 4.5 V 0 V _{CC} = 6.0 V 0 | 1000 500 400 | ns |

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

| Symbol | Parameter | Test Conditions | V _{CC} V | Guaranteed Limit | | | Unit |
|-----------------|--|--|----------------------|------------------|--------|---------|------|
| | | | | - 55 to 25°C | ≤ 85°C | ≤ 125°C | |
| V _{IH} | Minimum High-Level Input Voltage | V _{out} = 0.1 V or V _{CC} - 0.1 V I _{out} ≤ 20 μA | 2.0 | 1.5 | 1.5 | 1.5 | V |
| | | | 3.0 | 2.1 | 2.1 | 2.1 | |
| | | | 4.5 | 3.15 | 3.15 | 3.15 | |
| | | | 6.0 | 4.2 | 4.2 | 4.2 | |
| V _{IL} | Maximum Low-Level Input Voltage | V _{out} = 0.1 V or V _{CC} - 0.1 V I _{out} ≤ 20 μA | 2.0 | 0.5 | 0.5 | 0.5 | V |
| | | | 3.0 | 0.9 | 0.9 | 0.9 | |
| | | | 4.5 | 1.35 | 1.35 | 1.35 | |
| | | | 6.0 | 1.8 | 1.8 | 1.8 | |
| V _{OH} | Minimum High-Level Output Voltage, Q _A - Q _H | V _{in} = V _{IH} or V _{IL} I _{out} ≤ 20 μA | 2.0 | 1.9 | 1.9 | 1.9 | V |
| | | | 4.5 | 4.4 | 4.4 | 4.4 | |
| | | | 6.0 | 5.9 | 5.9 | 5.9 | |
| | | V _{in} = V _{IH} or V _{IL} I _{out} ≤ 2.4 mA I _{out} ≤ 6.0 mA I _{out} ≤ 7.8 mA | 3.0 | 2.48 | 2.34 | 2.2 | |
| | | | 4.5 | 3.98 | 3.84 | 3.7 | |
| | | | 6.0 | 5.48 | 5.34 | 5.2 | |
| V _{OL} | Maximum Low-Level Output Voltage, Q _A - Q _H | V _{in} = V _{IH} or V _{IL} I _{out} ≤ 20 μA | 2.0 | 0.1 | 0.1 | 0.1 | V |
| | | | 4.5 | 0.1 | 0.1 | 0.1 | |
| | | | 6.0 | 0.1 | 0.1 | 0.1 | |
| | | V _{in} = V _{IH} or V _{IL} I _{out} ≤ 2.4 mA I _{out} ≤ 6.0 mA I _{out} ≤ 7.8 mA | 3.0 | 0.26 | 0.33 | 0.4 | |
| | | | 4.5 | 0.26 | 0.33 | 0.4 | |
| | | | 6.0 | 0.26 | 0.33 | 0.4 | |

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

| Symbol | Parameter | Test Conditions | V _{CC} V | Guaranteed Limit | | | Unit |
|---------------------------|--|--|----------------------|------------------|--------|---------|------|
| | | | | - 55 to 25°C | ≤ 85°C | ≤ 125°C | |
| V _{OH} | Minimum High-Level Output Voltage, SQ _H | V _{in} = V _{IH} or V _{IL} I _{out} ≤ 20 μA | 2.0 | 1.9 | 1.9 | 1.9 | V |
| | | | 4.5 | 4.4 | 4.4 | 4.4 | |
| | | | 6.0 | 5.9 | 5.9 | 5.9 | |
| | | V _{in} = V _{IH} or V _{IL} I _{out} ≤ 2.4 mA I _{out} ≤ 4.0 mA I _{out} ≤ 5.2 mA | 3.0 | 2.98 | 2.34 | 2.2 | |
| | | | 4.5 | 3.98 | 3.84 | 3.7 | |
| | | | 6.0 | 5.48 | 5.34 | 5.2 | |
| V _{OL} | Maximum Low-Level Output Voltage, SQ _H | V _{in} = V _{IH} or V _{IL} I _{out} ≤ 20 μA | 2.0 | 0.1 | 0.1 | 0.1 | V |
| | | | 4.5 | 0.1 | 0.1 | 0.1 | |
| | | | 6.0 | 0.1 | 0.1 | 0.1 | |
| | | V _{in} = V _{IH} or V _{IL} I _{out} ≤ 2.4 mA I _{out} ≤ 4.0 mA I _{out} ≤ 5.2 mA | 3.0 | 0.26 | 0.33 | 0.4 | |
| | | | 4.5 | 0.26 | 0.33 | 0.4 | |
| | | | 6.0 | 0.26 | 0.33 | 0.4 | |
| I _{in} | Maximum Input Leakage Current | V _{in} = V _{CC} or GND | 6.0 | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| I _{OZ} | Maximum Three-State Leakage Current, Q _A – Q _H | Output in High-Impedance State V _{in} = V _{IL} or V _{IH} V _{out} = V _{CC} or GND | 6.0 | ± 0.5 | ± 5.0 | ± 10 | μA |
| I _{CC} (DL129/D) | Maximum Quiescent Supply Current (per Package) | V _{in} = V _{CC} or GND I _{out} = 0 μA | 6.0 | 4.0 | 40 | 160 | μA |

NOTE: Information on typical parametric values can be found in Chapter 2 of the ON Semiconductor High-Speed CMOS Data Book

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, Input t_r = t_f = 6.0 ns)

| Symbol | Parameter | V _{CC} V | Guaranteed Limit | | | Unit |
|--|--|----------------------|------------------|--------|---------|------|
| | | | - 55 to 25°C | ≤ 85°C | ≤ 125°C | |
| f _{max} | Maximum Clock Frequency (50% Duty Cycle) (Figures 1 and 7) | 2.0 | 6.0 | 4.8 | 4.0 | MHz |
| | | 3.0 | 15 | 10 | 8.0 | |
| | | 4.5 | 30 | 24 | 20 | |
| | | 6.0 | 35 | 28 | 24 | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Shift Clock to SQ _H (Figures 1 and 7) | 2.0 | 140 | 175 | 210 | ns |
| | | 3.0 | 100 | 125 | 150 | |
| | | 4.5 | 28 | 35 | 42 | |
| | | 6.0 | 24 | 30 | 36 | |
| t _{PHL} | Maximum Propagation Delay, Reset to SQ _H (Figures 2 and 7) | 2.0 | 145 | 180 | 220 | ns |
| | | 3.0 | 100 | 125 | 150 | |
| | | 4.5 | 29 | 36 | 44 | |
| | | 6.0 | 25 | 31 | 38 | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Latch Clock to Q _A – Q _H (Figures 3 and 7) | 2.0 | 140 | 175 | 210 | ns |
| | | 3.0 | 100 | 125 | 150 | |
| | | 4.5 | 28 | 35 | 42 | |
| | | 6.0 | 24 | 30 | 36 | |
| t _{PLZ} , t _{PHZ} | Maximum Propagation Delay, Output Enable to Q _A – Q _H (Figures 4 and 8) | 2.0 | 150 | 190 | 225 | ns |
| | | 3.0 | 100 | 125 | 150 | |
| | | 4.5 | 30 | 38 | 45 | |
| | | 6.0 | 26 | 33 | 38 | |
| t _{PZL} , t _{PZH} | Maximum Propagation Delay, Output Enable to Q _A – Q _H (Figures 4 and 8) | 2.0 | 135 | 170 | 205 | ns |
| | | 3.0 | 90 | 110 | 130 | |
| | | 4.5 | 27 | 34 | 41 | |
| | | 6.0 | 23 | 29 | 35 | |
| t _{TLH} , t _{THL} | Maximum Output Transition Time, Q _A – Q _H (Figures 3 and 7) | 2.0 | 60 | 75 | 90 | ns |
| | | 3.0 | 23 | 27 | 31 | |
| | | 4.5 | 12 | 15 | 18 | |
| | | 6.0 | 10 | 13 | 15 | |

AC ELECTRICAL CHARACTERISTICS ($C_L = 50$ pF, Input $t_r = t_f = 6.0$ ns)

| Symbol | Parameter | V _{CC} V | Guaranteed Limit | | | Unit |
|--|--|----------------------|------------------|--------|---------|------|
| | | | - 55 to 25°C | ≤ 85°C | ≤ 125°C | |
| t _{TLH} , t _{THL} | Maximum Output Transition Time, SQ _H (Figures 1 and 7) | 2.0 | 75 | 95 | 110 | ns |
| | | 3.0 | 27 | 32 | 36 | |
| | | 4.5 | 15 | 19 | 22 | |
| | | 6.0 | 13 | 16 | 19 | |
| C _{in} | Maximum Input Capacitance | — | 10 | 10 | 10 | pF |
| C _{out} | Maximum Three-State Output Capacitance (Output in High-Impedance State), Q _A – Q _H | — | 15 | 15 | 15 | pF |

NOTE: For propagation delays with loads other than 50 pF, and information on typical parametric values, see Chapter 2 of the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

| C _{PD} | Power Dissipation Capacitance (Per Package)* | Typical @ 25°C, V _{CC} = 5.0 V | | pF |
|-----------------|--|---|--|----|
| | | 300 | | |
| | | | | |

* Used to determine the no-load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$. For load considerations, see Chapter 2 of the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

TIMING REQUIREMENTS (Input $t_r = t_f = 6.0$ ns)

| Symbol | Parameter | V _{CC} V | Guaranteed Limit | | | Unit |
|---------------------------------|--|----------------------|-------------------|--------|---------|------|
| | | | 25°C to - 55°C | ≤ 85°C | ≤ 125°C | |
| t _{su} | Minimum Setup Time, Serial Data Input A to Shift Clock (Figure 5) | 2.0 | 50 | 65 | 75 | ns |
| | | 3.0 | 40 | 50 | 60 | |
| | | 4.5 | 10 | 13 | 15 | |
| | | 6.0 | 9.0 | 11 | 13 | |
| t _{su} | Minimum Setup Time, Shift Clock to Latch Clock (Figure 6) | 2.0 | 75 | 95 | 110 | ns |
| | | 3.0 | 60 | 70 | 80 | |
| | | 4.5 | 15 | 19 | 22 | |
| | | 6.0 | 13 | 16 | 19 | |
| t _h | Minimum Hold Time, Shift Clock to Serial Data Input A (Figure 5) | 2.0 | 5.0 | 5.0 | 5.0 | ns |
| | | 3.0 | 5.0 | 5.0 | 5.0 | |
| | | 4.5 | 5.0 | 5.0 | 5.0 | |
| | | 6.0 | 5.0 | 5.0 | 5.0 | |
| t _{rec} | Minimum Recovery Time, Reset Inactive to Shift Clock (Figure 2) | 2.0 | 50 | 65 | 75 | ns |
| | | 3.0 | 40 | 50 | 60 | |
| | | 4.5 | 10 | 13 | 15 | |
| | | 6.0 | 9.0 | 11 | 13 | |
| t _w | Minimum Pulse Width, Reset (Figure 2) | 2.0 | 60 | 75 | 90 | ns |
| | | 3.0 | 45 | 60 | 70 | |
| | | 4.5 | 12 | 15 | 18 | |
| | | 6.0 | 10 | 13 | 15 | |
| t _w | Minimum Pulse Width, Shift Clock (Figure 1) | 2.0 | 50 | 65 | 75 | ns |
| | | 3.0 | 40 | 50 | 60 | |
| | | 4.5 | 10 | 13 | 15 | |
| | | 6.0 | 9.0 | 11 | 13 | |
| t _w | Minimum Pulse Width, Latch Clock (Figure 6) | 2.0 | 50 | 65 | 75 | ns |
| | | 3.0 | 40 | 50 | 60 | |
| | | 4.5 | 10 | 13 | 15 | |
| | | 6.0 | 9.0 | 11 | 13 | |
| t _r , t _f | Maximum Input Rise and Fall Times (Figure 1) | 2.0 | 1000 | 1000 | 1000 | ns |
| | | 3.0 | 800 | 800 | 800 | |
| | | 4.5 | 500 | 500 | 500 | |
| | | 6.0 | 400 | 400 | 400 | |

FUNCTION TABLE

| Operation | Inputs | | | | | Resulting Function | | | |
|--|--------|----------------|-------------|-------------|---------------|--|---------------------------------|---------------------------------|--|
| | Reset | Serial Input A | Shift Clock | Latch Clock | Output Enable | Shift Register Contents | Latch Register Contents | Serial Output SQ _H | Parallel Outputs Q _A – Q _H |
| Reset shift register | L | X | X | L, H, ↓ | L | L | U | L | U |
| Shift data into shift register | H | D | ↑ | L, H, ↓ | L | D SR _A ; SR _N SR _{N+1} | U | SR _G SR _H | U |
| Shift register remains unchanged | H | X | L, H, ↓ | L, H, ↓ | L | U | U | U | U |
| Transfer shift register contents to latch register | H | X | L, H, ↓ | ↑ | L | U | SR _N LR _N | U | SR _N |
| Latch register remains unchanged | X | X | X | L, H, ↓ | L | * | U | * | U |
| Enable parallel outputs | X | X | X | X | L | * | ** | * | Enabled |
| Force outputs into high impedance state | X | X | X | X | H | * | ** | * | Z |

SR = shift register contents
 LR = latch register contents

D = data (L, H) logic level
 U = remains unchanged

↑ = Low-to-High
 ↓ = High-to-Low

* = depends on Reset and Shift Clock inputs
 ** = depends on Latch Clock input

PIN DESCRIPTIONS

INPUTS

A (Pin 14)

Serial Data Input. The data on this pin is shifted into the 8-bit serial shift register.

CONTROL INPUTS

Shift Clock (Pin 11)

Shift Register Clock Input. A low-to-high transition on this input causes the data at the Serial Input pin to be shifted into the 8-bit shift register.

Reset (Pin 10)

Active-low, Asynchronous, Shift Register Reset Input. A low on this pin resets the shift register portion of this device only. The 8-bit latch is not affected.

Latch Clock (Pin 12)

Storage Latch Clock Input. A low-to-high transition on this input latches the shift register data.

Output Enable (Pin 13)

Active-low Output Enable. A low on this input allows the data from the latches to be presented at the outputs. A high on this input forces the outputs (Q_A–Q_H) into the high-impedance state. The serial output is not affected by this control unit.

OUTPUTS

Q_A – Q_H (Pins 15, 1, 2, 3, 4, 5, 6, 7)

Noninverted, 3-state, latch outputs.

SQ_H (Pin 9)

Noninverted, Serial Data Output. This is the output of the eighth stage of the 8-bit shift register. This output does not have three-state capability.

SWITCHING WAVEFORMS

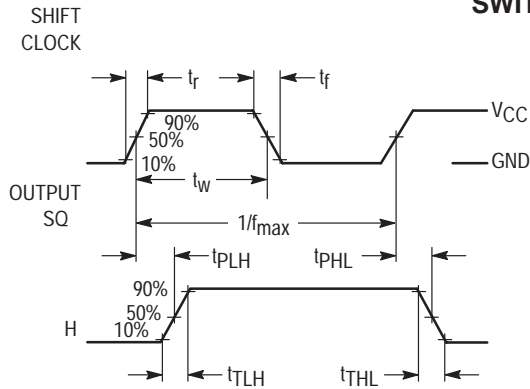


Figure 1.

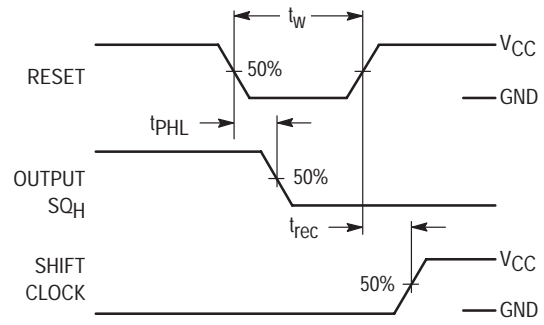


Figure 2.

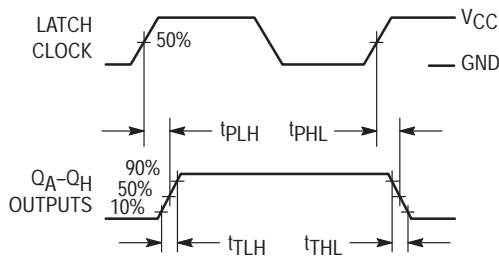


Figure 3.

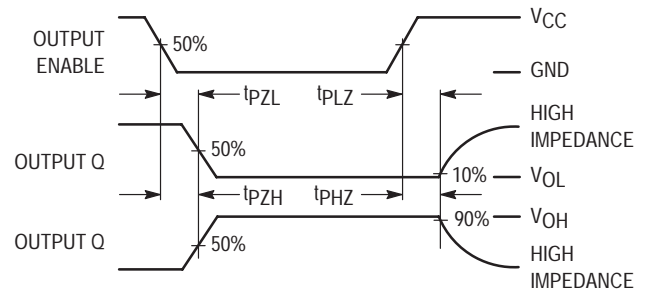


Figure 4.

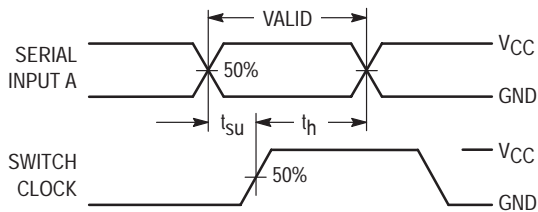


Figure 5.

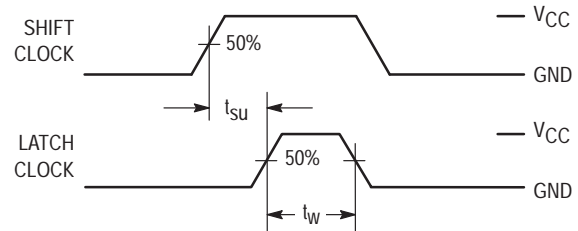
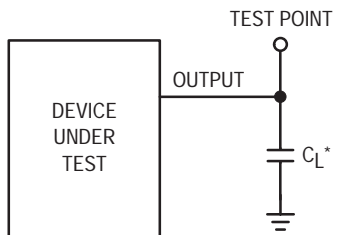


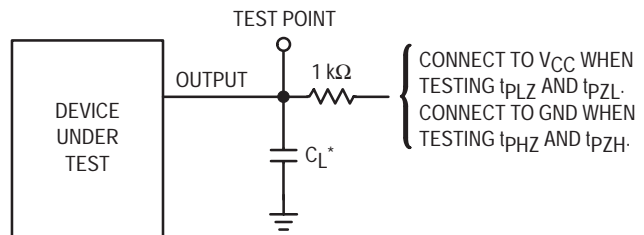
Figure 6.

TEST CIRCUITS



*Includes all probe and jig capacitance

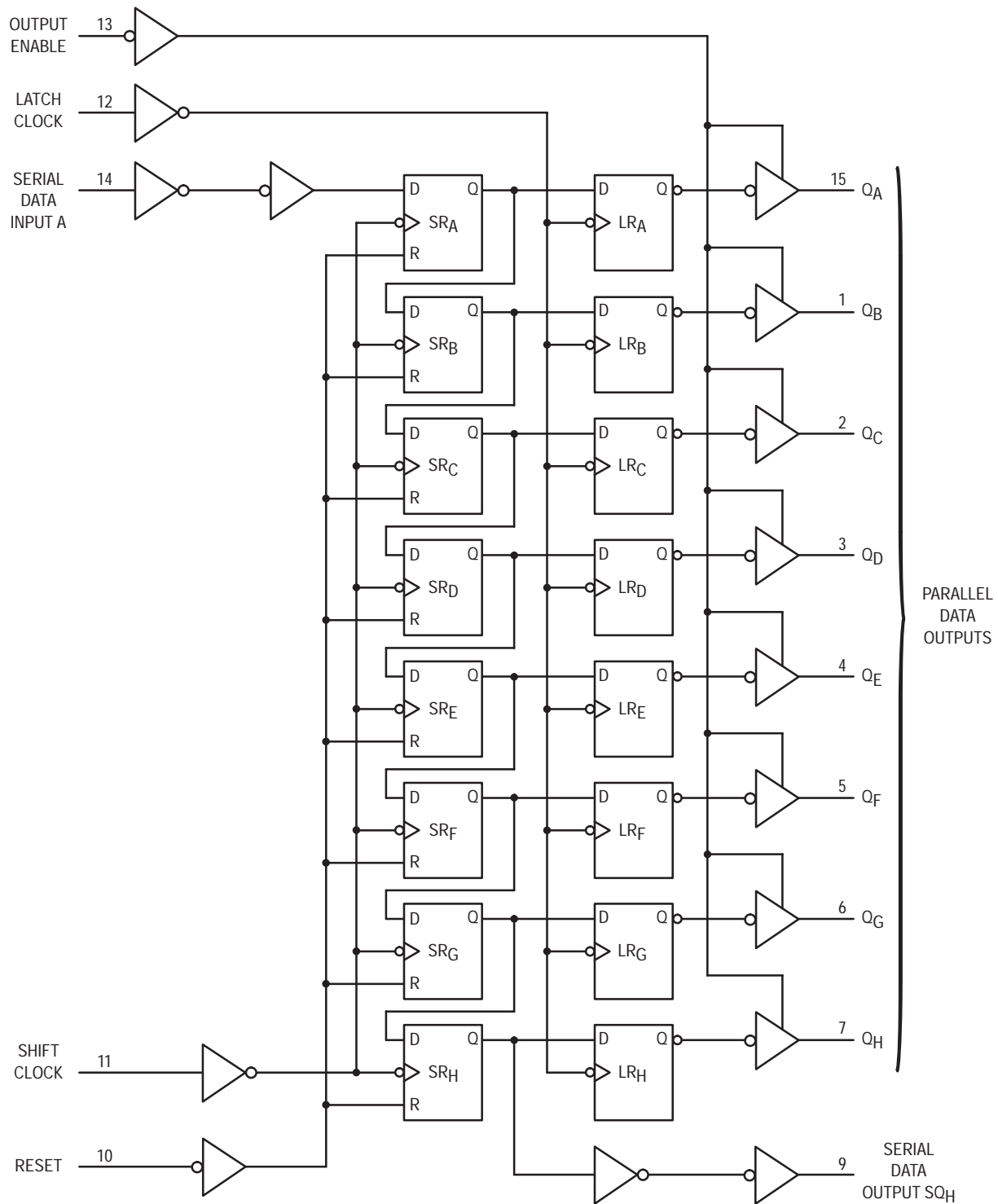
Figure 7.



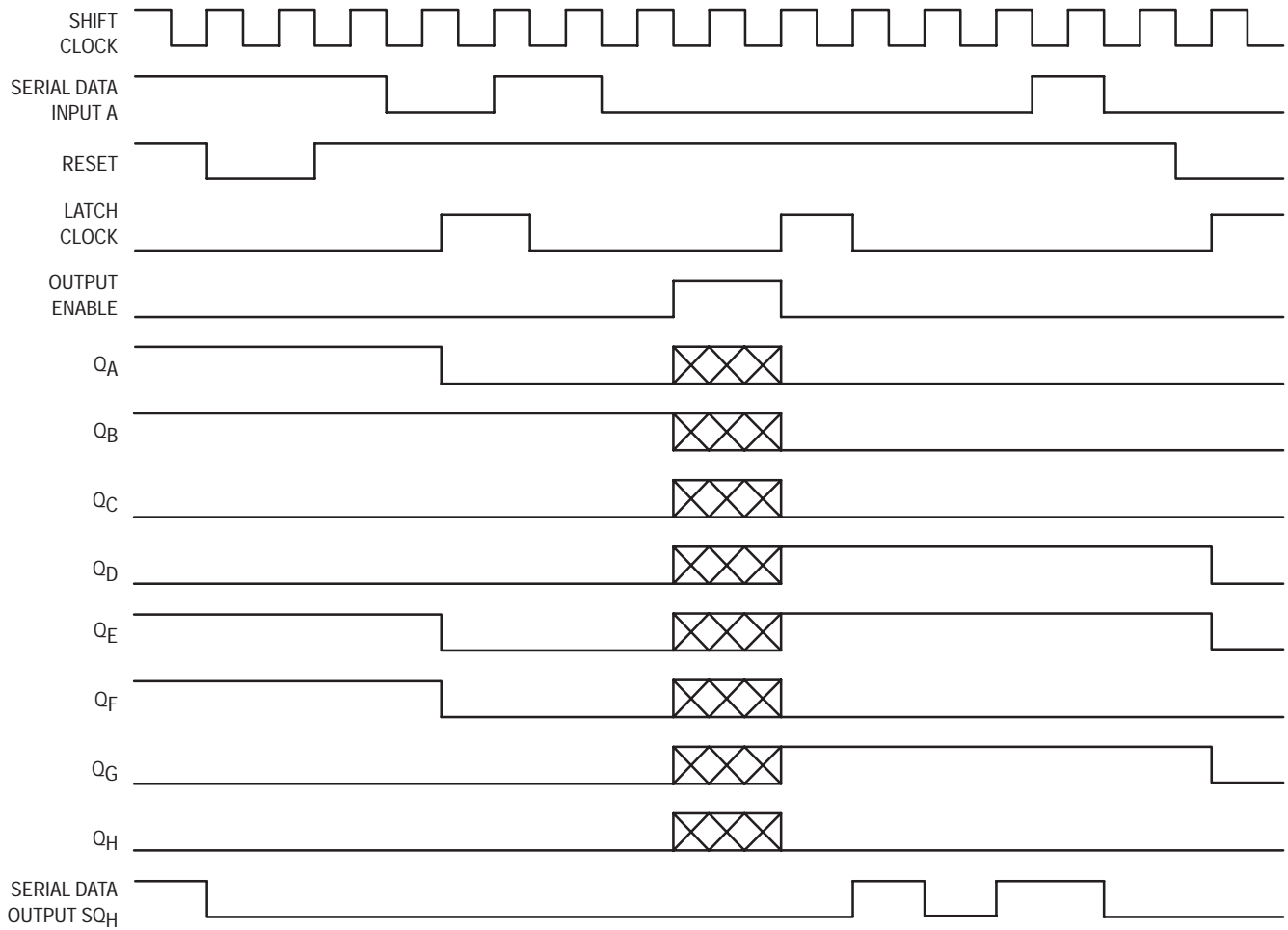
*Includes all probe and jig capacitance


Figure 8.

EXPANDED LOGIC DIAGRAM



TIMING DIAGRAM



NOTE:  implies that the output is in a high-impedance state.

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[74HC164T14-13](#) [TPIC6C596PWRG4](#) [STPIC6D595MTR](#) [STP08CP05MTR](#) [CD74HC123E](#) [74HC164D.653](#) [74HC165D.653](#)
[74HCT165D.652](#) [74HCT164D.652](#)